74HC40105 4-bit x 16-word FIFO register

Rev. 5 — 19 April 2019

1. General description

The 74HC40105 is a first-in/first-out (FIFO) "elastic" storage register that can store 16 4-bit words. It can handle input and output data at different shifting rates. This feature makes it particularly useful as a buffer between asynchronous systems. Each word position in the register is clocked by a control flip-flop, which stores a marker bit. A logic 1 signifies that the data at that position is filled and a logic 0 denotes a vacancy in that position. The control flip-flop detects the state of the preceding flip-flop and communicates its own status to the succeeding flip-flop. When a control flip-flop is in the logic 0 state and sees a logic 1 in the preceding flip-flop, it generates a clock pulse. The clock pulse transfers data from the preceding four data latches into its own four data latches and resets the preceding flip-flop to logic 0. The first and last control flip-flops have buffered outputs. All empty locations "bubble" automatically to the input end, and all valid data ripples through to the output end. As a result, the status of the first control flip-flop (data-in ready output - DIR) indicates if the FIFO is full. The status of the last flip-flop (data-out ready output - DOR) indicates whether the FIFO contains data. As the earliest data is removed from the bottom of the data stack (output end), all data entered later will automatically ripple toward the output. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- · Independent asynchronous inputs and outputs
- Expandable in either direction
- Reset capability
- Status indicators on inputs and outputs
- 3-state outputs
- CMOS input levels
- Complies with JEDEC standard JESD7A
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

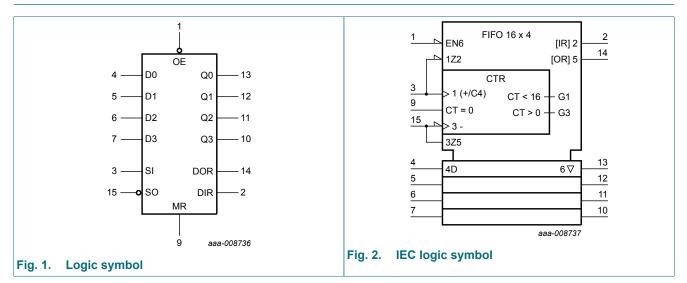
3. Ordering information

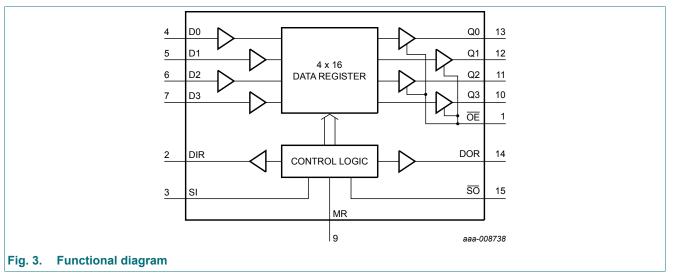
Table 1. Ordering information

| Type number | umber Package | | | | | | | |
|-------------|-------------------|------|---|----------|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | |
| 74HC40105D | -40 °C to +125 °C | | plastic small outline package; 16 leads; body width 3.9 mm | SOT109-1 | | | | |

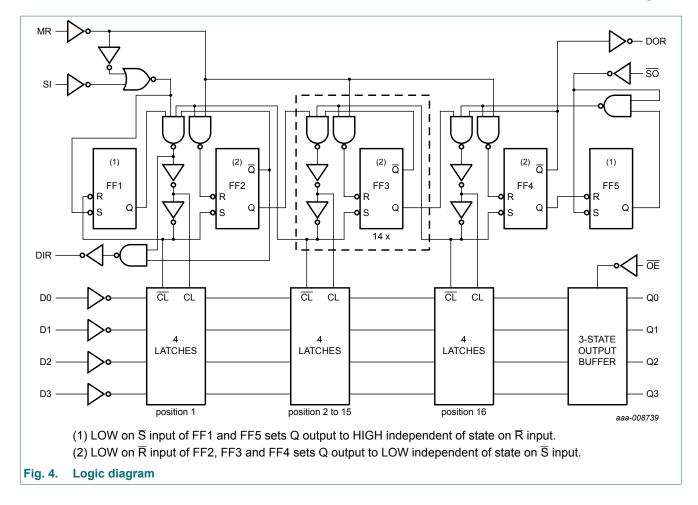


4. Functional diagram

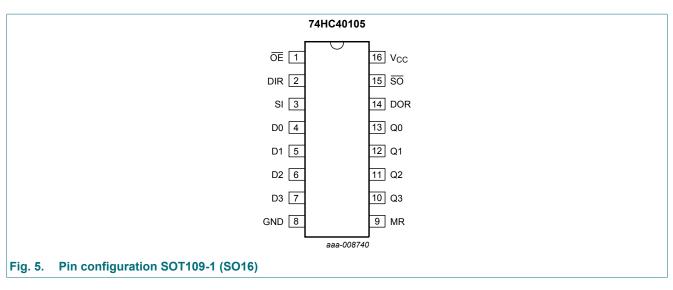




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5. Pinning information



5.1. Pinning

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| Table 2. Pin description | Table 2. Pin description | | | | | | | | |
|--------------------------|--------------------------|---|--|--|--|--|--|--|--|
| Symbol | Pin | Description | | | | | | | |
| ŌĒ | 1 | output enable input (active LOW) | | | | | | | |
| DIR | 2 | data-in-ready output | | | | | | | |
| SI | 3 | shift-in input (LOW-to-HIGH, edge triggered) | | | | | | | |
| D0 to D3 | 4, 5, 6, 7 | parallel data input | | | | | | | |
| GND | 8 | ground (0 V) | | | | | | | |
| MR | 9 | asynchronous master-reset input (active HIGH) | | | | | | | |
| Q0 to Q3 | 13, 12, 11, 10 | data output | | | | | | | |
| DOR | 14 | data-out-ready output | | | | | | | |
| SO | 15 | shift-out input (HIGH-to-LOW, edge triggered) | | | | | | | |
| V _{CC} | 16 | supply voltage | | | | | | | |

5.2. Pin description

6. Functional description

6.1. Inputs and outputs

Data inputs (D0 to D3)

As there is no weighting of the inputs, any input can be assigned as the MSB. The size of the FIFO memory can be reduced from the 4 x 16 configuration. For example, it can be reduced to 3 x 16, down to 1 x 16, by tying unused data input pins to V_{CC} or GND.

Data outputs (Q0 to Q3)

As there is no weighting of the outputs, any output can be assigned as the MSB. The size of the FIFO memory can be reduced from the 4 x 16 configuration as described for data inputs. In a reduced format, the unused data outputs pins must be left open circuit.

Master-reset (MR)

When MR is HIGH, the control functions within the FIFO are cleared, and date content is declared invalid. The data-in ready (DIR) flag is set HIGH and the data-out-ready (DOR) flag is set LOW. The output stage remains in the state of the last word that was shifted out, or in the random state existing at power-up.

Status flag outputs (DIR, DOR)

Two status flags, data-in-ready (DIR) and data-out-ready (DOR), indicate the status of the FIFO:

- 1. DIR = HIGH indicates that the input stage is empty and ready to accept valid data;
- DIR = LOW indicates that the FIFO is full or that a previous shift-in operation is not complete (busy);
- **3.** DOR = HIGH assures valid data is present at the outputs Q0 to Q3 (does not indicate that new data is awaiting transfer into the output stage);
- **4.** DOR = LOW indicates that the output stage is busy or there is no valid data.

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Shift-in control (SI)

Data is loaded into the input stage on a LOW-to-HIGH transition of SI. It also triggers an automatic data transfer process (ripple through). If SI is held HIGH during reset, data is loaded at the falling edge of the MR signal.

Shift-out control (SO)

A HIGH-to-LOW transition of \overline{SO} causes the DOR flags to go LOW. A HIGH-to-LOW transition of \overline{SO} causes upstream data to move into the output stage, and empty locations to move towards the input stage (bubble-up).

Output enable (OE)

The outputs Q0 to Q3 are enabled when \overline{OE} = LOW. When \overline{OE} = HIGH the outputs are in the high impedance OFF-state.

6.2. Data input

Following power-up, the master-reset (MR) input is pulsed HIGH to clear the FIFO memory (see Fig. 6). The data-in-ready flag (DIR = HIGH) indicates that the FIFO input stage is empty and ready to receive data. When DIR is valid (HIGH), data present at D0 to D3 can be shifted-in using the SI control input. With SI = HIGH, data is shifted into the input stage. DIR going LOW provides a busy indication. The data remains at the first location in the FIFO until DIR is set to HIGH and data moves through the FIFO to the output stage, or to the last empty location. If the FIFO is not full after the SI pulse, DIR again becomes valid (HIGH) to indicate that space is available in the FIFO. The DIR flag remains LOW if the FIFO is full (see Fig. 7). To complete the shift-in process, the SI use must be made LOW. With the FIFO full, SI can be held HIGH until a shift-out (SO) pulse occurs. Then, following a shift-out of data, an empty location appears at the FIFO input and DIR goes HIGH to allow the next data to be shifted-in. This data remains at the first FIFO location until SI goes LOW (see Fig. 8).

6.3. Data transfer

After data has been transferred from the input stage of the FIFO following SI = LOW, data moves through the FIFO asynchronously and is stacked at the output end of the register. Empty locations appear at the input end of the FIFO as data moves through the device.

6.4. Data output

The data-out-ready flag (DOR = HIGH) indicates that there is valid data at the output (Q0 to Q3). The initial master-reset at power-on (MR = HIGH) sets DOR to LOW (see Fig. 6). After MR = LOW, data shifted into the FIFO moves through to the output stage causing DOR to go HIGH. As the DOR flag goes HIGH, data can be shifted-out using the \overline{SO} = HIGH, data in the output stage is shifted out. DOR going LOW provides a busy indication. When \overline{SO} is made LOW, data moves through the FIFO to fill the output stage and an empty location appears at the input stage. When the output stage is filled DOR goes HIGH, but if the last of the valid data has been shifted-out leaving the FIFO empty the DOR flag remains LOW (see Fig. 10). With the FIFO empty, the last word that was shifted-out is latched at the output Q0 to Q3.

With the FIFO empty, the \overline{SO} input can be held HIGH until the SI control input is used. Following an SI pulse, data moves through the FIFO to the output stage, resulting in the DOR flag pulsing HIGH and a shift-out of data occurring. The \overline{SO} control must be made LOW before additional data can be shifted-out (see Fig. 13).

6.5. High-speed burst mode

Assuming the shift-in/shift-out pulses are not applied until the respective status flags are valid, it follows that the status flags determine the shift-in/shift-out rates. However, without the status flags, a high-speed burst can be implemented. In this mode, pulse widths determine the burst-in/burst-out

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rates of the shift-in/shift-out inputs. Burst rates of 35 MHz can be obtained. Shift pulses can be applied without regard to the status flags but shift-in pulses that would overflow the storage capacity of the FIFO are not allowed (see Fig. 11 and Fig. 12).

6.6. Expanded format

With the addition of a logic gate, the FIFO is easily expanded to increase word length (see Fig. 18). The basic operation and timing are identical to a single FIFO, except for an additional gate delay on the flag outputs. If during application, the following occurs:

 SI is held HIGH when the FIFO is empty, some additional logic is required to produce a composite DIR pulse (see Fig. 8 and Fig. 19).

Due to the part-to-part spread of the ripple through time, the SI signals of FIFO A and FIFO B do not always coincide. As a result, the AND-gate does not produce a composite flag signal. The solution is given in Fig. 19. The 74HC40105 is easily cascaded to increase the word capacity and no external components are needed. In the cascaded configuration, the FIFOs perform all necessary communications and timing. The minimum flag pulse widths and the flag delays determine the intercommunication speed. The data rate of cascaded devices is typically 25 MHz. Word-capacity can be expanded to and beyond 32-words x 4-bits (see Fig. 20).

7. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Мах | Unit |
|------------------|-------------------------|---|------|------|------|
| V _{CC} | supply voltage | | -0.5 | +7 | V |
| I _{IK} | input clamping current | $V_{I} < -0.5 V \text{ or } V_{I} > V_{CC} + 0.5 V$ [1] | - | ±20 | mA |
| Ι _{ΟΚ} | output clamping current | $V_{\rm O} < -0.5 \text{ V or } V_{\rm O} > V_{\rm CC} + 0.5 \text{ V}$ [1] | - | ±20 | mA |
| lo | output current | $V_{\rm O}$ = -0.5 V to (V _{CC} + 0.5 V) | - | ±25 | mA |
| I _{CC} | supply current | | - | +50 | mA |
| I _{GND} | ground current | | -50 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | [2] | - | 500 | mW |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO16 packages: above 70 °C the value of Ptot derates linearly with 8 mW/K.

8. Recommended operating conditions

Table 4. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|-------------------------------------|-------------------------|-----|------|-----------------|------|
| V _{CC} | supply voltage | | 2.0 | 5.0 | 6.0 | V |
| VI | input voltage | | 0 | - | V _{CC} | V |
| Vo | output voltage | | 0 | - | V _{CC} | V |
| T _{amb} | ambient temperature | | -40 | +25 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 2.0 V | - | - | 625 | ns/V |
| | | V _{CC} = 4.5 V | - | 1.67 | 139 | ns/V |
| | | V _{CC} = 6.0 V | - | - | 83 | ns/V |

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9. Static characteristics

Table 5. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | 25 °C | | | °C to 5 °C | -40 °C to +125 °C | | Unit |
|----------------------------|-------------------------------------|--|------|-------|------|------|---------------|----------------------|-------|------|
| | | | Min | Тур | Мах | Min | Мах | Min | Max | |
| VIH | HIGH-level | V _{CC} = 2.0 V | 1.5 | 1.2 | - | 1.5 | - | 1.5 | - | V |
| | input voltage | V _{CC} = 4.5 V | 3.15 | 2.4 | - | 3.15 | - | 3.15 | - | V |
| | | V _{CC} = 6.0 V | 4.2 | 3.2 | - | 4.2 | - | 4.2 | - | V |
| V _{IL} | LOW-level | V _{CC} = 2.0 V | - | 0.8 | 0.5 | - | 0.5 | - | 0.5 | V |
| | input voltage | V _{CC} = 4.5 V | - | 2.1 | 1.35 | - | 1.35 | - | 1.35 | V |
| | | V _{CC} = 6.0 V | - | 2.8 | 1.8 | - | 1.8 | - | 1.8 | V |
| V _{OH} HIGH-level | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | | | | | | |
| | output voltage | I _O = -20 μA; V _{CC} = 2.0 V | 1.9 | 2.0 | - | 1.9 | - | 1.9 | - | V |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | V |
| | | I _O = -20 μA; V _{CC} = 6.0 V | 5.9 | 6.0 | - | 5.9 | - | 5.9 | - | V |
| | | I _O = -4 mA; V _{CC} = 4.5 V | 3.98 | 4.32 | - | 3.84 | - | 3.7 | - | V |
| | | I _O = -5.2 mA; V _{CC} = 6.0 V | 5.48 | 5.81 | - | 5.34 | - | 5.2 | - | V |
| V _{OL} | LOW-level | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | | | | | |
| | output voltage | I _O = 20 μA; V _{CC} = 2.0 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 6.0 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 4 mA; V _{CC} = 4.5 V | - | 0.15 | 0.26 | - | 0.33 | - | 0.4 | V |
| | | I _O = 5.2 mA; V _{CC} = 6.0 V | - | 0.15 | 0.26 | - | 0.33 | - | 0.4 | V |
| I _I | input leakage current | $V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V | - | - | ±0.1 | - | ±1.0 | - | ±1.0 | μA |
| I _{OZ} | OFF-state output current | $V_{I} = V_{IH} \text{ or } V_{IL};$ $V_{O} = V_{CC} \text{ or } GND; V_{CC} = 6.0 \text{ V}$ | - | - | ±0.5 | - | ±5.0 | - | ±10.0 | μA |
| I _{CC} | supply current | $V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V | - | - | 8 | - | 80 | - | 160 | μA |
| CI | input capacitance | | - | 3.5 | - | - | - | - | - | pF |

10. Dynamic characteristics

Table 6. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit, see Fig. 17.

| Symbol | Parameter | Conditions | | 25 °C | | | °C to 5 °C | -40 °C to +125 °C | | Unit |
|------------------|-------------------|---|-----|-------|------|-----|---------------|----------------------|------|------|
| | | | Min | Тур | Мах | Min | Мах | Min | Мах | |
| t _{pd} | propagation | MR to DIR or DOR; see Fig. 6 [1] | | | | | | | | |
| | delay | V _{CC} = 2.0 V | - | 52 | 175 | - | 220 | - | 265 | ns |
| | | V _{CC} = 4.5 V | - | 19 | 35 | - | 44 | - | 53 | ns |
| | | V _{CC} = 5 V; C _L = 15 pF | - | 16 | - | - | - | - | - | ns |
| | | V _{CC} = 6.0 V | - | 15 | 30 | - | 37 | - | 45 | ns |
| | | SO to Qn; see Fig. 9[1] | | | | | | | | |
| | | V _{CC} = 2.0 V | - | 116 | 400 | - | 500 | - | 600 | ns |
| | | V _{CC} = 4.5 V | - | 42 | 80 | - | 100 | - | 120 | ns |
| | | V _{CC} = 5 V; C _L = 15 pF | - | 37 | - | - | - | - | - | ns |
| | | V _{CC} = 6.0 V | - | 34 | 68 | - | 85 | - | 102 | ns |
| t _{PHL} | HIGH to LOW | SI to DIR; see Fig. 7 [1] | | | | | | | | |
| | propagation delay | V _{CC} = 2.0 V | - | 52 | 210 | - | 265 | - | 315 | ns |
| | uelay | V _{CC} = 4.5 V | - | 19 | 42 | - | 53 | - | 63 | ns |
| | | V _{CC} = 5 V; C _L = 15 pF | - | 16 | - | - | - | - | - | ns |
| | | V _{CC} = 6.0 V | - | 15 | 36 | - | 45 | - | 54 | ns |
| | | SO to DOR; see Fig. 10[1] | | | | | | | | |
| | | V _{CC} = 2.0 V | - | 55 | 210 | - | 265 | - | 315 | ns |
| | | V _{CC} = 4.5 V | - | 20 | 42 | - | 53 | - | 63 | ns |
| | | V _{CC} = 5 V; C _L = 15 pF | - | 17 | - | - | - | - | - | ns |
| | | V _{CC} = 6.0 V | - | 16 | 36 | - | 45 | - | 54 | ns |
| t _{PLH} | LOW to HIGH | SI to DOR; see <u>Fig. 13</u> [1][2] | | | | | | | | |
| | propagation | V _{CC} = 2.0 V | - | 564 | 2000 | - | 2500 | - | 3000 | ns |
| | delay | V _{CC} = 4.5 V | - | 205 | 400 | - | 500 | - | 600 | ns |
| | | V _{CC} = 6.0 V | - | 165 | 340 | - | 425 | - | 510 | ns |
| | | SO to DIR; see Fig. 8 [1][3] | | | | | | | | |
| | | V _{CC} = 2.0 V | - | 701 | 2500 | - | 3125 | - | 3750 | ns |
| | | V _{CC} = 4.5 V | - | 255 | 500 | - | 625 | - | 750 | ns |
| | | V _{CC} = 6.0 V | - | 204 | 425 | - | 532 | - | 638 | ns |
| t _{en} | enable time | OE to Qn; see <u>Fig. 15</u> [4] | | | | | | | | - |
| | | V _{CC} = 2.0 V | - | 41 | 150 | - | 190 | - | 225 | ns |
| | | V _{CC} = 4.5 V | - | 15 | 30 | - | 38 | - | 45 | ns |
| | | V _{CC} = 6.0 V | - | 12 | 26 | - | 33 | - | 38 | ns |
| t _{dis} | disable time | OE to Qn; see <u>Fig. 15</u> [5] | | | | | | | | + |
| | | V _{CC} = 2.0 V | - | 41 | 140 | - | 175 | - | 210 | ns |
| | | V _{CC} = 4.5 V | - | 15 | 28 | - | 35 | - | 42 | ns |
| | | V _{CC} = 6.0 V | - | 12 | 24 | - | 30 | - | 36 | ns |

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| Symbol | Parameter | Conditions | | 25 °C | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|------------------|-----------------|------------------------------|-----|-------|-----|---------------------|-----|----------------------|-----|------|
| | | | Min | Тур | Max | Min | Max | Min | Max | |
| tt | transition time | Qn; see <u>Fig. 9</u> [6] | | | | | | | | |
| | | V _{CC} = 2.0 V | - | 19 | 75 | - | 95 | - | 110 | ns |
| | | V _{CC} = 4.5 V | - | 7 | 15 | - | 19 | - | 22 | ns |
| | | V _{CC} = 6.0 V | - | 6 | 13 | - | 16 | - | 19 | ns |
| t _W | pulse width | SI HIGH or LOW; see Fig. 7 | | | | | | | | |
| | | V _{CC} = 2.0 V | 80 | 19 | - | 100 | - | 120 | - | ns |
| | | V _{CC} = 4.5 V | 16 | 7 | - | 20 | - | 24 | - | ns |
| | | V _{CC} = 6.0 V | 14 | 6 | - | 17 | - | 20 | - | ns |
| | | SO HIGH or LOW; see Fig. 10 | | | | | | | | |
| | | V _{CC} = 2.0 V | 120 | 39 | - | 150 | - | 180 | - | ns |
| | | $V_{CC} = 4.5 V$ | 24 | 14 | - | 30 | - | 36 | - | ns |
| | | $V_{\rm CC} = 6.0 \text{ V}$ | 20 | 11 | - | 26 | - | 31 | - | ns |
| | | DIR HIGH; see Fig. 8 | | | | | | | | |
| | | V _{CC} = 2.0 V | 12 | 58 | 180 | 10 | 225 | 10 | 270 | ns |
| | | V _{CC} = 4.5 V | 6 | 21 | 36 | 5 | 45 | 5 | 54 | ns |
| | | $V_{\rm CC} = 6.0 \rm V$ | 5 | 17 | 31 | 4 | 38 | 4 | 46 | ns |
| | | DOR LOW; see Fig. 13 | | | | | | | | |
| | | V _{CC} = 2.0 V | 12 | 55 | 170 | 10 | 215 | 10 | 255 | ns |
| | | V _{CC} = 4.5 V | 6 | 20 | 34 | 5 | 43 | 5 | 51 | ns |
| | | $V_{\rm CC} = 6.0 \rm V$ | 5 | 16 | 29 | 4 | 37 | 4 | 43 | ns |
| | | MR HIGH; see Fig. 6 | | | | | | | | |
| | | $V_{CC} = 2.0 V$ | 80 | 22 | - | 100 | - | 120 | - | ns |
| | | $V_{\rm CC} = 4.5 \rm V$ | 16 | 8 | - | 20 | _ | 24 | - | ns |
| | | $V_{\rm CC} = 6.0 \rm V$ | 14 | 6 | _ | 17 | - | 20 | - | ns |
| t _{rec} | recovery time | MR to SI; see Fig. 14 | | | | | | | | |
| 100 | , | $V_{\rm CC} = 2.0 \rm V$ | 50 | 14 | _ | 65 | - | 75 | - | ns |
| | | $V_{\rm CC} = 4.5 \text{V}$ | 10 | 5 | - | 13 | _ | 15 | - | ns |
| | | $V_{CC} = 6.0 V$ | 9 | 4 | _ | 11 | - | 13 | _ | ns |
| t _{su} | set-up time | Dn to SI; see Fig. 16 | - | | | | | | | |
| -su | | $V_{\rm CC} = 2.0 \rm V$ | -5 | -39 | _ | -5 | - | -5 | _ | ns |
| | | $V_{CC} = 4.5 V$ | -5 | -14 | _ | -5 | _ | -5 | - | ns |
| | | $V_{CC} = 6.0 V$ | -5 | -11 | _ | -5 | _ | -5 | _ | ns |
| t _h | hold time | Dn to SI; see Fig. 16 | • | | | - | | | | |
| | | $V_{\rm CC} = 2.0 \rm V$ | 125 | 44 | _ | 155 | - | 190 | - | ns |
| | | $V_{\rm CC} = 4.5 V$ | 25 | 16 | - | 31 | _ | 38 | - | ns |
| | | $V_{CC} = 6.0 V$ | 21 | 13 | - | 26 | - | 32 | - | ns |

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| Symbol Parameter | | Conditions | | 25 °C | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|---------------------------------------|-------------------------------------|---|-----|-------|-----|---------------------|-----|----------------------|-----|------|
| | | | Min | Тур | Max | Min | Max | Min | Max | |
| f _{max} maximum frequency | | SI, \overline{SO} using flags or burst mode; see $\underline{Fig. 7}$, $\underline{Fig. 10}$, $\underline{Fig. 11}$ and $\underline{Fig. 12}$ | | | | | | | | |
| | | V _{CC} = 2.0 V | 3.6 | 10 | - | 2.8 | - | 2.4 | - | MHz |
| | | V _{CC} = 4.5 V | 18 | 30 | - | 14 | - | 12 | - | MHz |
| | | V _{CC} = 5 V; C _L = 15 pF | - | 33 | - | - | - | - | - | MHz |
| | | V _{CC} = 6.0 V | 21 | 36 | - | 16 | - | 14 | - | MHz |
| | | SI, \overline{SO} cascaded; see $\underline{Fig. 7}$ and $\underline{Fig. 10}$ | | | | | | | | |
| | | V _{CC} = 2.0 V | 3.6 | 10 | - | 2.8 | - | 2.4 | - | MHz |
| | | $V_{CC} = 4.5 V$ | 18 | 30 | - | 14 | - | 12 | - | MHz |
| | | V _{CC} = 6.0 V | 21 | 36 | - | 16 | - | 14 | - | MHz |
| C _{PD} | power dissipation capacitance | $V_{I} = GND \text{ to } V_{CC}$ [7] | - | 134 | - | - | - | - | - | pF |

 t_{pd} is the same as t_{PLH} and $t_{\text{PHL}}.$ This is the ripple through delay. [1] [2]

This is the bubble-up delay. [3]

[4] t_{en} is the same as t_{PZH} and t_{PZL} .

[5] t_{dis} is the same as t_{PLZ} and t_{PHZ}.

[6] [7]

 t_{dis} is the same as t_{TLL} and t_{TLH} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

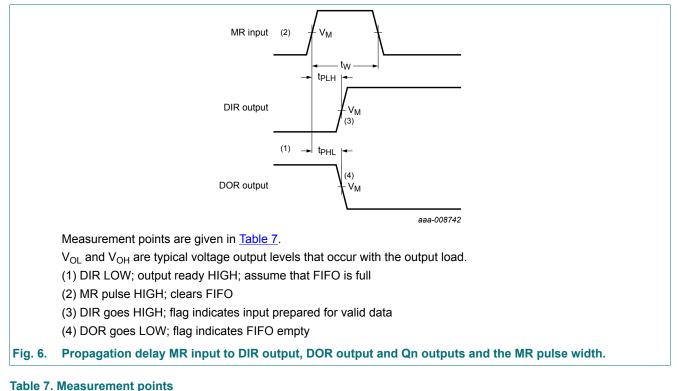
 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

10.1. Waveforms and test circuit

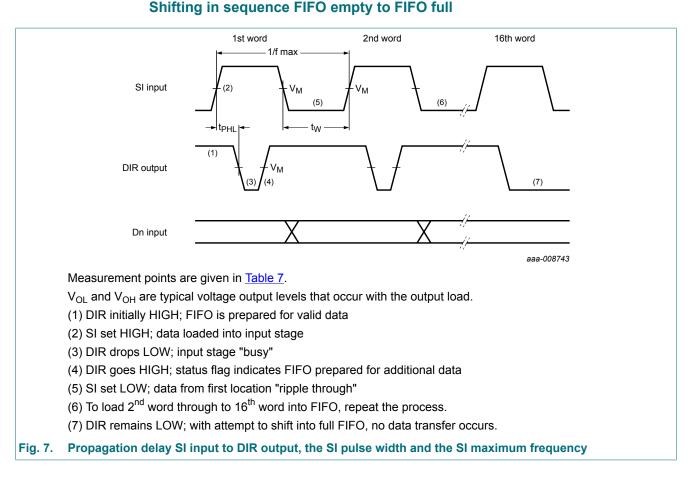
Master reset applied with FIFO full



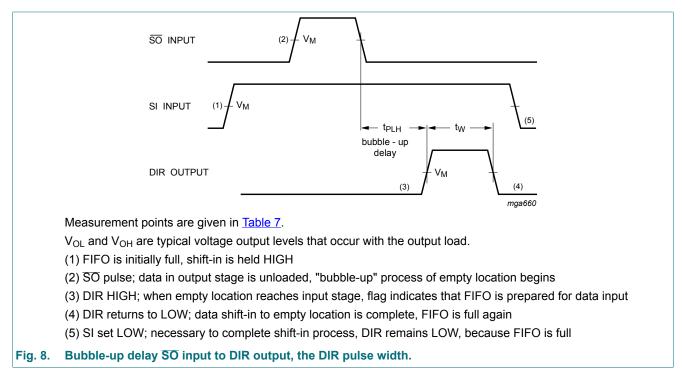
| Input | Output | | |
|--------------------|--------------------|--------------------|--------------------|
| V _M | V _M | V _X | V _Y |
| 0.5V _{CC} | 0.5V _{CC} | 0.1V _{CC} | 0.9V _{CC} |

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4-bit x 16-word FIFO register

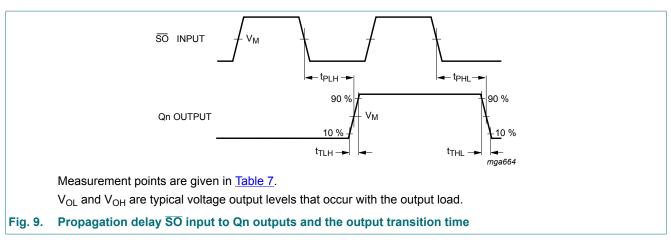


With FIFO full; SI held HIGH in anticipation of empty location

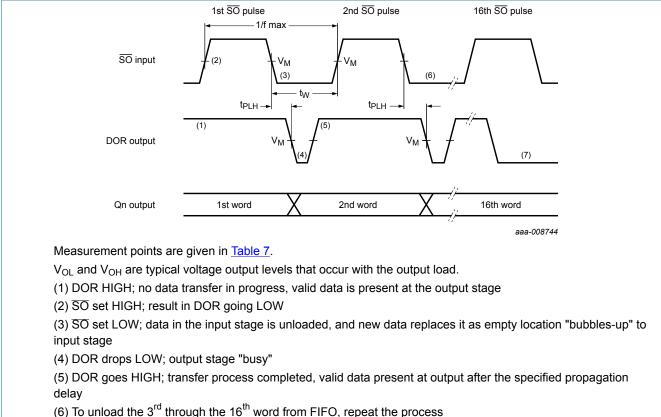


4-bit x 16-word FIFO register







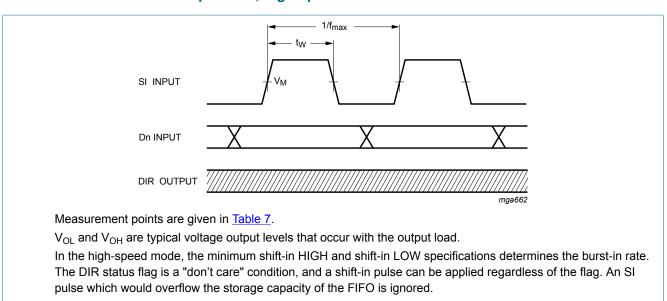


(7) DOR remains LOW; FIFO is empty

Fig. 10. Propagation delay SO input to DOR output, the SO pulse width and the SO maximum frequency.

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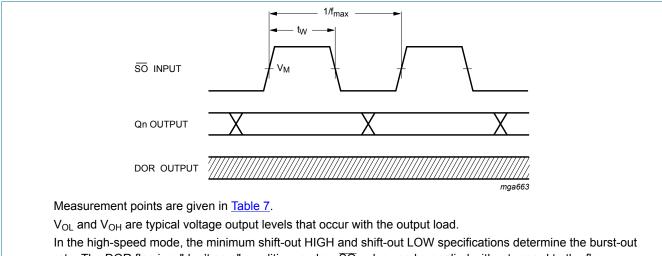
4-bit x 16-word FIFO register



Shift-in operation; high-speed burst mode



Shift-out operation; high-speed burst mode

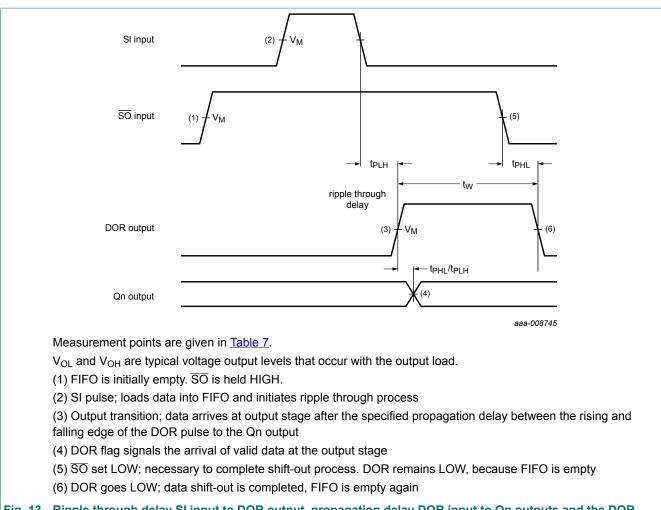


rate. The DOR flag is a "don't care" condition, and an SO pulse can be applied without regard to the flag.

Fig. 12. The SO pulse width and the SO maximum frequency, in high-speed shift-out burst mode

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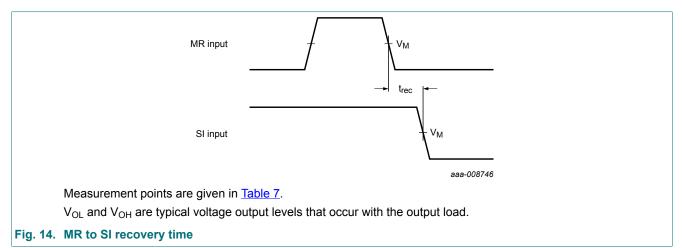
4-bit x 16-word FIFO register



With FIFO empty; SO is held HIGH in anticipation

Fig. 13. Ripple through delay SI input to DOR output, propagation delay DOR input to Qn outputs and the DOR pulse width

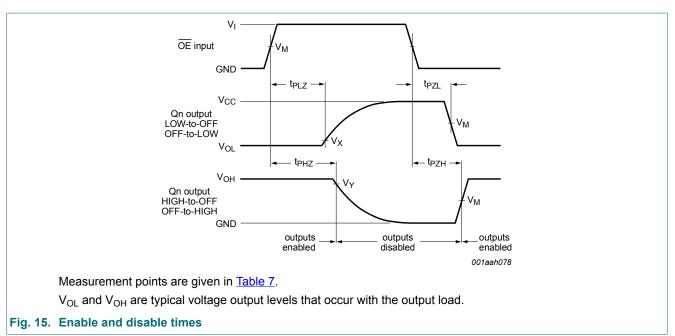
MR to SI recovery time



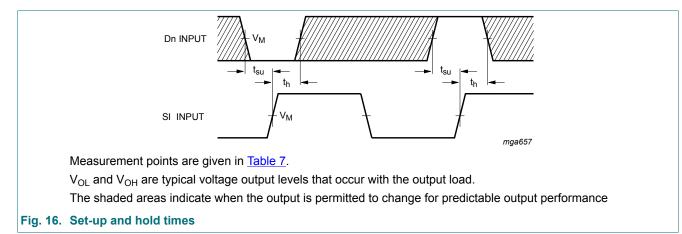
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4-bit x 16-word FIFO register

Enable and disable times



Set-up and hold times

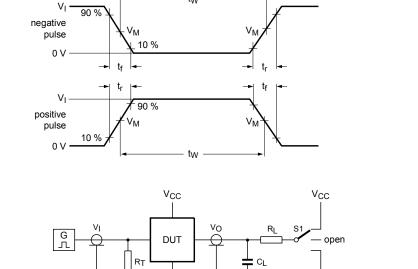


Product data sheet

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4-bit x 16-word FIFO register





001aad983

Test data is given in <u>Table 8</u>.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

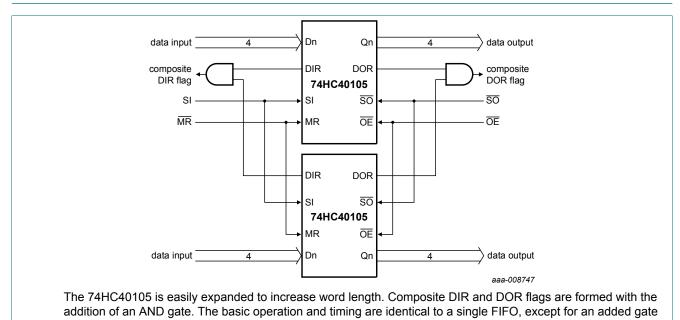
Fig. 17. Test circuit for measuring switching times

Table 8. Test data

| Input | | Load | | S1 position | | | |
|-----------------|---------------------------------|--------------|------|-------------------------------------|-------------------------------------|-------------------------------------|--|
| VI | t _r , t _f | CL | RL | t _{PHL} , t _{PLH} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} | |
| V _{CC} | 6 ns | 15 pF, 50 pF | 1 kΩ | open | GND | V _{CC} | |

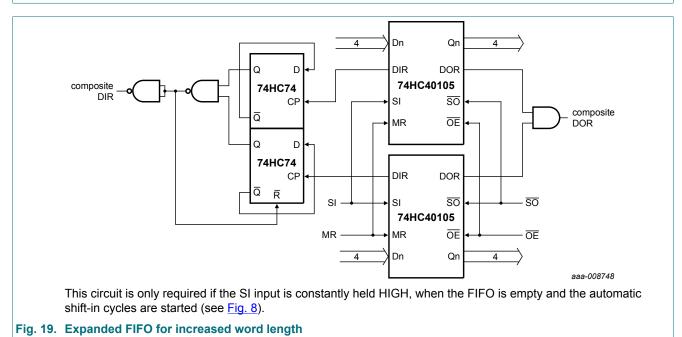
4-bit x 16-word FIFO register

11. Application information



delay on the flags.

Fig. 18. Expanded FIFO for increased word length; 16 words x 8 bits

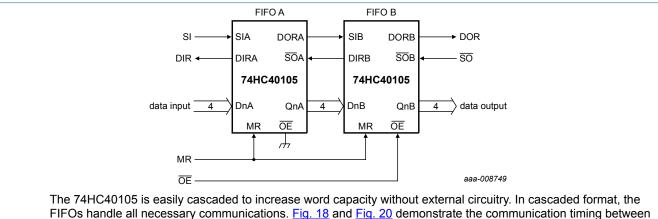


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11.1. Expanded format

Fig. 20 shows two cascaded FIFOs providing a capacity of 32 words x 4 bits. Fig. 21 shows the signals on the nodes of both FIFOs after the application of the SI pulse, when both FIFOs are initially empty. After a ripple through delay, data arrives at the output of FIFO A. Due to SOA being HIGH, a DORA pulse is generated. The DORA pulse width and the timing between the rising edge of DORA and QnA satisfy the requirements of SIB and DnB. After a second ripple through delay data arrives at the output of FIFO B.

Fig. 22 shows the signals on the nodes of both FIFOs after the application of the SOB pulse, when both FIFOs are initially full. After a bubble-up delay, a DIRB pulse is generated, which acts as a SOA pulse for FIFO A. One word is transferred from the output of FIFO A to the input of FIFO B. The pulse width of DORB satisfy the requirements of the SOA pulse for FIFO A. After a second bubble-up delay, an empty space arrives at DnA, at which time DIRA goes HIGH. Fig. 23 shows the waveforms at all external nodes of both FIFOs during a complete shift-in and shift-out sequence.



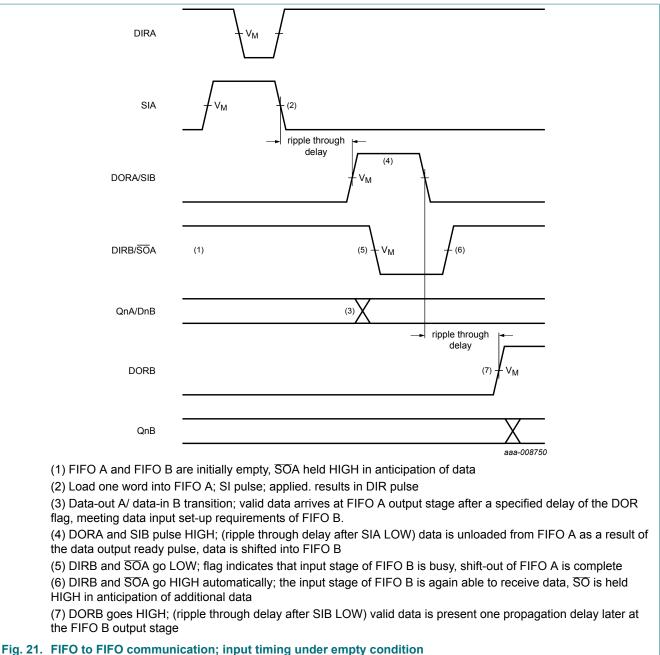
FIFOs handle all necessary communications. Fig. 18 and Fig. 20 demonstrate the communication timing between FIFO A and FIFO B. Fig. 23 provides an overview of pulses and timing of two cascaded FIFOs, when shifted full and shifted empty again.

Fig. 20. Cascading for increased word capacity; 32 words x 4 bits

74HC40105

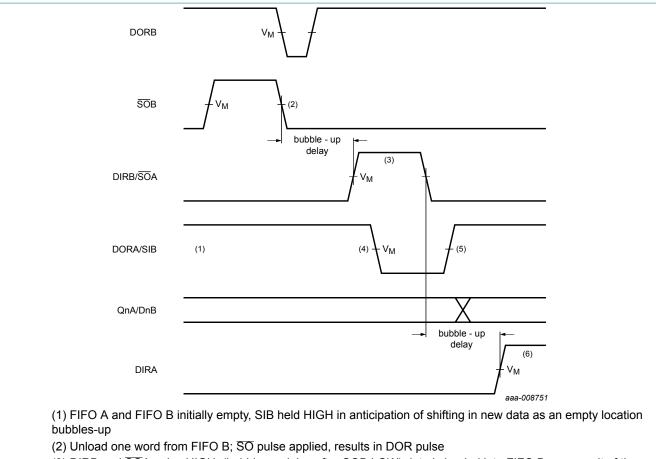
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4-bit x 16-word FIFO register



74HC40105

4-bit x 16-word FIFO register



(3) DIRB and SOA pulse HIGH; (bubble-up delay after SOB LOW) data is loaded into FIFO B as a result of the DIR pulse, data is shifted out of FIFO A

(4) DORA and SIB go LOW; flag indicates that the output stage of FIFO A is busy, shift-in of FIFO B is complete (5) DORA and SIB go HIGH; flag indicates that valid data is again available at FIFO A output stage, SIB is held HIGH, awaiting bubble-up of empty location.

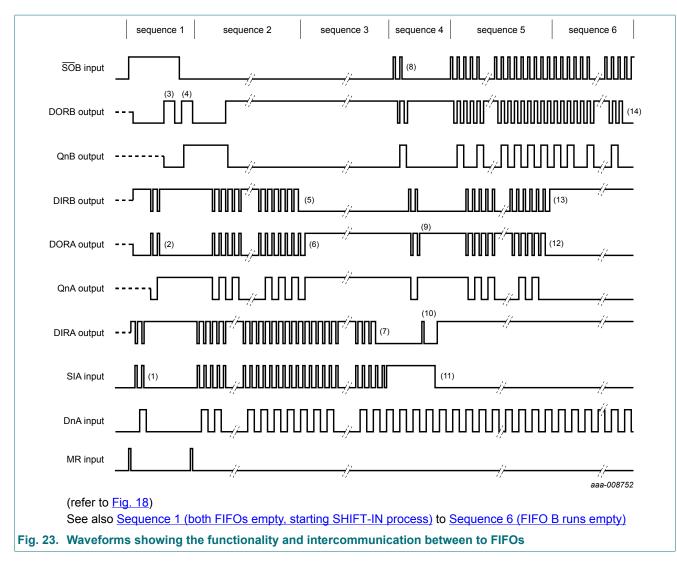
(6) DIRA goes HIGH; (bubble-up delay after SOA LOW) an empty location is present at input stage of FIFO A

Fig. 22. FIFO to FIFO communication; output timing under full condition

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4-bit x 16-word FIFO register



Sequence 1 (both FIFOs empty, starting SHIFT-IN process)

After an MR pulse has been applied, FIFO A and FIFO B are empty. The DOR flags of FIFO A and FIFO B go LOW due to no valid data being present at the outputs. The DIR flags are set HIGH due to the FIFOs being ready to accept data. SOB is held HIGH and two SIA pulses are applied (1). These pulses allow two data words to ripple through the output stage of FIFO A and the input stage of FIFO B (2). When data arrives at the output of FIFO B, a DORB pulse is generated (3). When SOB goes LOW, the first bit is shifted out and a second bit ripples through to the output after which DORB goes high (4).

Sequence 2 (FIFO B runs full)

After the MR pulse, a series of 16 SI pulses are applied. When 16 words are shifted in, DIRB remains LOW due to FIFO B being full (5). DORA goes LOW due to FIFO A being empty.

Sequence 3 (FIFO A runs full)

When 17 words are shifted in, DORA remains HIGH due to valid data remaining at the output of FIFO A. QnA remains HIGH, being the polarity of the 17th word (6). After the 32th SI pulse, DIR remains LOW and both FIFOs are full (7). Additional pulses have no effect.

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4-bit x 16-word FIFO register

Sequence 4 (both FIFOs full, starting SHIFT-OUT)

SIA is held HIGH and two SOB pulses are applied (8). These pulses shift out two words and thus allow two empty locations to bubble-up to the input stage of FIFO B, and proceed to FIFO A (9). When the first empty location arrives at the input of FIFO A, a DIRA pulse is generated (10) and a new word is shifted into FIFO A. SIA is made LOW and now the second empty location reaches the input stage of FIFO A, after which DIRA remains HIGH (11).

Sequence 5 (FIFO A runs empty)

At the start of sequence 5, FIFO A contains 15 valid words due to two words being shifted out and one word being shifted in, in sequence 4. And additional series of SOB pulses are applied. After 15 SOB pulses, all words from FIFO A are shifted in FIFO B. DORA remains LOW (12).

Sequence 6 (FIFO B runs empty)

After the next \overline{SOB} pulse, DIRB remains HIGH due to the input stage of FIFO B being empty (13). After another 15 \overline{SOB} pulses, DORB remains LOW due to both FIFOs being empty (14). Additional \overline{SOB} pulses have no effect. The last word remains available at the output Qn.

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12. Package outline

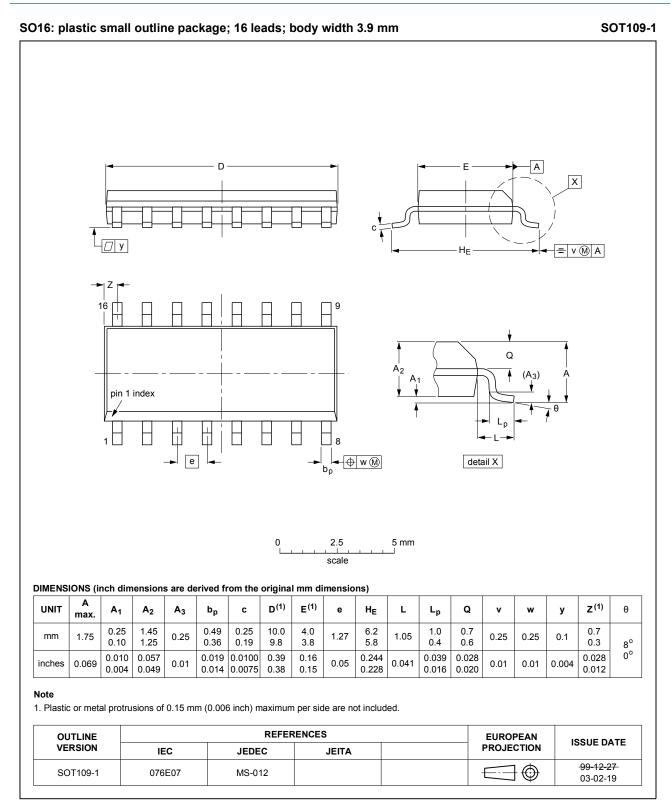


Fig. 24. Package outline SOT109-1 (SO16)

74HC40105

13. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| FIFO | First In First Out |
| HBM | Human Body Model |
| MM | Machine Model |
| MSB | Most Significant Bit |

14. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | | |
|-----------------------|---|--|--------------------------------|-----------------------|--|--|--|
| 74HC40105 v.5 | 20190419 | Product data sheet | - | 74HC_HCT40105 v. 4 | | | |
| Modifications: | of Nexperia. • Legal texts h • Type number • Type number | ave been adapted to the ne 74HCT40105D (SOT109- | ICT40105DB (SOT338-1) removed. | | | | |
| 74HC_HCT40105 v. 4 | 20160129 | Product data sheet | - | 74HC_HCT40105 v. 3 | | | |
| Modifications: | Type number | s 74HC40105N and 74HC | T40105N (SOT38 | 3-4) removed. | | | |
| 74HC_HCT40105 v. 3 | 20130925 | Product data sheet | - | 74HC_HCT40105_CNV v.2 | | | |
| Modifications: | The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. | | | | | | |
| 74HC_HCT40105_CNV v.2 | 19980123 | Product specification | - | - | | | |

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4-bit x 16-word FIFO register

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|-----------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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